



A-9837E  
PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of:

Lars Ivar SAMUELSON et al.

Appln. No.: 10/613,071

Group Art Unit: 2811

Filed: July 7, 2003

For: NANOSTRUCTURES AND METHODS FOR MANUFACTURING  
THE SAME

\* \* \*

INFORMATION DISCLOSURE STATEMENT

Commissioner of Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

Pursuant to 37 C.F.R. § 1.56, and without any assertion as to materiality or prior art effect, the documents listed on the attached Form PTO-1449 are hereby cited.

Documents AA-AB, AE, AJ, AO, QD, and TH-TK on the attached List were cited in the International Search Report (copy attached) of counterpart PCT Application No.

PCT/GB2004/000037.

Respectfully submitted,

By:   
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September 29, 2004

FORM PTO-1449

Atty. Docket No.

Appln. No.

LIST OF DOCUMENTS CITED BY APPLICANT

A-9837E

10/613,071

Applicant

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## U.S. PATENT DOCUMENTS

Examiner Initial		Document Number	Date	Name	Class	Sub-class	Filing Date
	BA	6,190,634	2/20/01	Lieber et al.	423	439	
	BB	6,159,742	12/12/00	Lieber et al.	436	164	
	BC	5,997,832	12/7/99	Lieber et al.	423	249	
	BD	5,840,435	11/24/98	Lieber et al.	428	689	
	BE	5,252,835	10/12/93	Lieber et al.	250	492.1	

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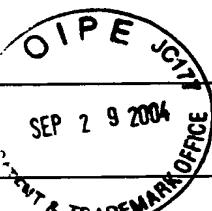
Examiner Initial		Document Number	Date	Country	Class	Sub-class	Translation
	BF	WO 02/080280	10/10/02	WIPO			

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	BG	Duan, X., et al., "Laser-Assisted Catalytic Growth of Single-Crystal Compound Semiconductor Nanowires", <u>Abstracts of Papers of the Amer. Chem. Soc.</u> , Vol. 219, March 26, 2000, pp. 676-Inor Part 1.
	BH	Duan, X. et al., "Laser Assisted Catalytic Growth of Semiconductor Nanowires for Nanoscale Electronic Optoelectronic Device Application", <u>Abstracts of Papers of the Amer. Chem. Soc.</u> , Vol. 221, April 1, 2001, pp. 644-Inor Part 1.
	BI	Lieber, C., "Semiconductor Nanowires: Building Blocks for Nanoscale Science and Technology", <u>Abstracts of Papers of the Amer. Chem. Soc.</u> , Vol. 222, August 1, 2001, pp. 383-Phys Part 2.
	BJ	Huang, Y., et al., "Integrated Optoelectronics Assembled from Semiconductor Nanowires", <u>Abstracts of Papers of the Amer. Chem. Soc.</u> , Vol. 224, August 18, 2002, pp. 093-Phys - Part 2.
	BK	Hu, J. et al., "Chemistry and Physics in One Dimension: Synthesis and Properties of Nanowires and Nanotubes", <u>Acc. Chem. Res.</u> , Vol. 32, No. 5, February 20, 1999, p. 435-445.
	BL	Duan, X. et al., "General Synthesis of Compound Semiconductor Nanowires", <u>Advanced Materials</u> , Vol. 12, No. 4, January 1, 2000, pp. 298-302.
	BM	Duan, X., et al., "Synthesis and optical properties of gallium arsenide nanowires", <u>Applied Physics Letters</u> , Vol. 76, No. 9, February 28, 2000, pp. 1116-1118.
	BN	Cui, Y., et al., "Diameter-controlled synthesis of single-crystal silicon nanowires", <u>Applied Physics Letters</u> , Vol. 78, No. 15, April 9, 2001, pp. 2214-2216.

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.

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				<b>Applicant</b> <b>Lars Ivar SAMUELSON et al.</b>		
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	AA	<b>2002/0172820</b>	<b>11/21/02</b>	<b>Majumdar et al.</b>	<b>428</b>	<b>357</b>
	AB	<b>2002/0129761</b>	<b>9/19/02</b>	<b>Takami</b>	<b>117</b>	<b>73</b>
	AC	<b>5,362,972</b>	<b>11/8/94</b>	<b>Yazawa et al</b>	<b>257</b>	<b>13</b>
	AD	<b>5,332,910</b>	<b>7/26/94</b>	<b>Haraguchi et al.</b>	<b>257</b>	<b>13</b>
<b>FOREIGN PATENT DOCUMENTS</b>						
Examiner Initial		Document Number	Date	Country	Class	Sub-class
	AE	<b>WO 01/84238</b>	<b>11/8/01</b>	<b>WIPO</b>		
<b>OTHER</b> (including author, title, date, pertinent pages, etc.)						
	AF	<b>Yasawa, M. et al., "Heteroepitaxial Ultrafine Wire-Like Growth of InAs on GaAs Substrates", <u>Appl. Phys. Lett.</u>, Vol. 58, No. 10, March 11, 1991, pp. 1080-1082.</b>				
	AG	<b>Haraguchi, K. et al., "GaAs p-n junction formed in quantum wire crystals", <u>Applied Physics Letters</u>, Vol. 60, No. 6, February 10, 1992, pp. 745-747</b>				
	AH	<b>Yazawa, M., et al., "Effect of one monolayer of surface gold atoms on the epitaxial growth of InAs nanowhiskers", <u>Applied Physics Letters</u>, Vol. 61, October 26, 1992, pp. 2051-2053.</b>				
	AI	<b>Yazawa, M., "Nanocolumns composed of GaAs-InAs jointed whiskers and SiO<sub>2</sub> covers", <u>Applied Physics Letters</u>, Vol. 65, August 29, 1994, pp. 1157-1158</b>				
	AJ	<b>Sato, T., "Site-controlled growth of nanowhiskers", <u>Applied Physics Letters</u>, Vol. 66, January 9, 1995, pp. 159-161.</b>				
	AK	<b>Hiruma, K., et al., "Growth and optical properties of nanometer-scale GaAs and InAs whiskers", <u>Applied Physics Review</u>, Vol. 77, January 15, 1995, pp. 447-462.</b>				
	AL	<b>Hiruma K., et al., "Growth and Characterization of Nanometer-Scale GaAs, AlGaAs and GaAs/InAs Wires", <u>IEICE Trans. Electron.</u>, Vol. E77-C, No. 9, September 1, 1994, pp. 1420-1425.</b>				
	AM	<b>Hiruma, K. et al., "GaAs free-standing quantum-size wires", <u>Journal of Applied Physics</u>, Vol. 74, September 1, 1993, pp. 3162-3171.</b>				
	AN	<b>Haraguchi, K., et al., "Polarization dependence of light emitted from GaAs p-n junctions in quantum wire crystals", <u>Journal of Applied Physics</u>, Vol. 75, April 15, 1994, pp. 4220-4225.</b>				
	AO	<b>Hiruma, K., et al., "Self-organized growth of GaAs/InAs heterostructure nanocylinders by organometallic vapor phase epitaxy, <u>Journal of Crystal Growth</u>, Vol. 163, January 1, 1996, pp. 226-231.</b>				
	AP	<b>Lieber, C., "Nanowires as Building Blocks for Nanoscale Science and Technology", <u>Abstracts of Papers of the Amer. Chem Soc.</u>, Vol. 224, August 18, 2002, pp. 033-Comp Part 1.</b>				
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	CA	<b>6,307,241</b>	<b>10/23/01</b>	<b>Awschalom et al.</b>	<b>257</b>	<b>421</b>	
	CB	<b>5,196,396</b>	<b>3/23/93</b>	<b>Lieber</b>	<b>505</b>	<b>1</b>	
	CC	<b>6,716,409</b>	<b>4/6/04</b>	<b>Hafner et al.</b>	<b>423</b>	<b>447</b>	
<b>FOREIGN PATENT DOCUMENTS</b>							
Examiner Initial		Document Number	Date	Country	Class	Sub-class	Translation
	CD	<b>WO 03/005450</b>	<b>1/16/03</b>	<b>WIPO</b>			
<b>OTHER</b> (including author, title, date, pertinent pages, etc.)							
*	CE	<b>Gudiksen M.S., et al., "Diameter-selective synthesis of semiconductor nanowires", <i>J. Am. Chem. Soc.</i>, Vol. 122, August 22, 2000, pp. 8801-8802.</b>					
	CF	<b>Gudiksen M., et al., "Size-Dependent Photoluminescence from Single Indium Phosphide Nanowires", <i>Journal of Physical Chemistry B</i>, Vol. 106, No. 16, March 30, 2002, pp. 4036-4039.</b>					
*	CG	<b>Duan, X., et al., "Laser-Assisted Catalytic Growth of Single Crystal GaN Nanowires", <i>Journal of Amer. Chem. Soc.</i>, Vol. 122, NO. 1, December 18, 1999, pp. 188-189.</b>					
	CH	<b>Huang, Y., et al., "Gallium Nitride Nanowire Nanodevices", <i>Nano Letters</i>, Vol. 2, No. 2, January 11, 2002, pp. 81-82.</b>					
	CI	<b>Lieber C., "Nanowire Superlattices", <i>Nano Letters</i>, Vol. 2, No. 2, January 25, 2002, pp. 82-82.</b>					
	CJ	<b>Duan, X., et al., "Nonvolatile Memory and Programmable Logic from Molecule-Gated Nanowires", <i>Nano Letters</i>, Vol. 2, No. 5, May 1, 2002, pp. 487-490.</b>					
	CK	<b>Cui, Y., et al., "High Performance Silicon Nanowire Field Effect Transistors", <i>Nano Letters</i>, Vol. 3, No. 2, January 1, 2003, pp. 149-152.</b>					
	CL	<b>Zhong, Z., et al., "Synthesis of P-Type Gallium Nitride Nanowires for Electronic and Photonic Nanodevices", <i>Nano Letters</i>, Vol. 3, No. 3, February 20, 2003, pp. 343-346.</b>					
*	CM	<b>Hu, J., et al., "Controlled Growth and Electrical Properties of Heterojunctions of Carbon Nanotubes and Silicon Nanowires", <i>Nature</i>, Vol. 399, May 6, 1999, pp. 48-51.</b>					
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	DA	<b>6,743,408</b>	<b>6/1/04</b>	<b>Lieber et al.</b>	<b>423</b>	<b>447.1</b>	
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	DB	<b>WO 01/03208</b>	<b>1/11/01</b>	<b>WIPO</b>			
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	DC	Duan, X., et al., "Indium phosphide nanowires as building blocks for nanoscale electronic and optoelectronic devices", <u>Nature</u> , Vol. 409, January 4, 2001, pp. 66-69.					
	DD	Gudiksen M., et al., "Growth of nanowire superlattice structures for nanoscale photonics and electronics", <u>Nature</u> , Vol. 415, February 7, 2002, pp. 617-620.					
	DE	Lauhon, L., et al., "Epitaxial Core-Shell and Core-Multishell Nanowire Heterostructures", <u>Nature</u> , Vol. 420, No. 6911, November 7, 2002, pp. 57-61.					
	DF	Duan, X., "Single-nanowire electrically driven lasers", <u>Nature</u> , Vol. 421, January 16, 2003, pp. 241-244.					
	DG	Lieber, C., "The incredible shrinking circuit", <u>Sci. Am.</u> , Vol. 285, September 1, 2001, pp. 58-64.					
	DH	Morales, A., et al., "A Laser Ablation Method for the Synthesis of Crystalline Semiconductor Nanowires", <u>Science</u> , Vol. 279, January 9, 1998, pp. 208-211.					
	DJ	Cui Y., et al., "Functional Nanoscale Electronic Devices Assembled Using Silicon Nanowire Building Blocks", <u>Science</u> , Vol. 291, February 2, 2001, pp. 851-853.					
	DK	Wang, J., et al., "Highly Polarized Photoluminescence and Photodetection from Single Indium Phosphide Nanowires", <u>Science</u> , Vol. 293, No. 5534, August 24, 2001, pp. 1455-1457.					
	DL	Cui Y., et al., "Nanowire nanosensors for highly sensitive and selective detection of biological and chemical species", <u>Science</u> , Vol. 293, August 17, 2001, pp. 1289-1292.					
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	EA						
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	EB	<b>WO 97/31139</b>	<b>8/28/97</b>	<b>WIPO</b>			
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	EC	<b>Huang, Y., et al., "Logic Gates and Computation from Assembled Nanowire Building Blocks", <u>Science</u>, Vol. 294, November 9, 2001, pp. 1313-1317.</b>					
	ED	<b>Cui, Y., et al., "Doping and Electrical Transport in Silicon Nanowires", <u>The Journal of Physical Chemistry B</u>, Vol. 104, No. 22, May 11, 2000, pp. 5213-5216.</b>					
	EE	<b>Gudiksen M., et al., "Synthetic Control of the Diameter and Length of Single Crystal Semiconductor Nanowires", <u>The Journal of Physical Chemistry B</u>, Vol. 105, April 18, 2001, pp. 4062-4064.</b>					
	EF	<b>Morales, A. et al., "Rational Synthesis of Silicon Nanowires", <u>INOR</u>, 651, January 1, 2001.</b>					
	EG	<b>Wong E., et al., "Nanobeam Mechanics: Elasticity, Strength, and Toughness of Nanorods and Nanotubes", <u>Science</u>, Vol. 277, September 26, 1997, pp. 1971-1975.</b>					
	EH	<b>Dai, H., et al., "Synthesis and Characterization of Carbide Nanorods", <u>Nature</u>, Vol. 375, June 29, 1995, pp. 769-772.</b>					
	EI	<b>Junno, T., et al., "Controlled manipulation of nanoparticles with an atomic force microscope", <u>Applied Physics Letters</u>, Vol. 66, June 26, 1995, pp. 3627-3629.</b>					
	EJ	<b>Zwiller, V., et al., "Single quantum dots emit single photons at a time: Antibunching experiment", <u>Applied Physics Letters</u>, Vol. 78, No. 17, April 23, 2001, pp. 2476-2478.</b>					
	EK						
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	FB	<b>WO 95/02709</b>	<b>1/26/95</b>	<b>WIPO</b>			
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	FC	<b>Borgstrom, M., et al., "High peak-to-valley ratios observed in InAs/InP resonant tunneling quantum dot stacks", <u>Applied Physics Letters</u>, Vol. 78, No. 21, May 21, 2001, pp. 3232-3234.</b>					
	FD	<b>Thelander, et al., "Gold nanoparticle single-electron transistor with carbon nanotube leads", <u>Applied Physics Letters</u>, Vol. 79, No. 13, September 24, 2001, pp. 2106-2108.</b>					
	FE	<b>Ohlsson B.J., et al., "Size-, shape-, and position-controlled GaAs nano-whiskers", <u>Applied Physics Letters</u>, Vol. 79, No. 20, November 12, 2001, pp. 3335-3337.</b>					
	FF	<b>Bjork, M.T., et al., "One-dimensional heterostructures in semiconductor nanowhiskers", <u>Applied Physics Letters</u>, Vol. 80, No. 6, February 11, 2002, pp. 1058-1060.</b>					
	FG	<b>Persson, M.P. et al., "Electronic Structure of Nanometer-Scale GaAs Whiskers", <u>Applied Physics Letters</u>, Vol. 81, No. 7, August 12, 2002, pp. 1309-1311.</b>					
	FH	<b>Thelander, C., et al., "Single-Electron Transistors in Heterostructure Nanowires", <u>Applied Physics Letters</u>, Vol. 83, No. 10, September 8, 2003, pp. 2052-2054.</b>					
	FI	<b>Panayev, N., et al., "Sharp Exciton Emission From Single InAs Quantum Dots in GaAs Nanowires", <u>Applied Physics Letters</u>, Vol. 83, No. 11, September 15, 2003, pp. 2238-2240.</b>					
	FJ	<b>Bjork, M.T., "Nanowire resonant tunelling diodes", <u>Applied Physics Letters</u>, Vol. 81, No. 23, December 2, 2002, pp. 4458-4460.</b>					
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	GA						
<b>FOREIGN PATENT DOCUMENTS</b>							
Examiner Initial		Document Number	Date	Country	Class	Sub-class	Translation
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	GC	<b>Persson, A., "Oriented Growth of InAs-based Nanowhiskers", Diploma Work, Lund Institute of Technology, Lund University, May 29, 2001, pp. 1-48.</b>					
	GD	<b>Ohlsson, J., "Semiconductor Hetero- and Nanostructures", Doctoral Thesis, Lund Institute of Technology, Lund University, November 23, 2001.</b>					
	GE	<b>Thelander, C., "Quantum Devices from the Assembly of Zero-and One-Dimensional Building Blocks", Doctoral Thesis, Lund University, November 7, 2003.</b>					
	GF	<b>Ohlsson, B., et al., "Anisotropic GaAs island phase grown on flat GaP: A stranski-Krastanow-formed corrugated surface", Journal of Applied Physics, Vol. 89, No. 10, May 15, 2001, pp. 5726-5730.</b>					
	GG	<b>Magnusson, M., et al., "Gold nanoparticles: Production, reshaping, and thermal charging", Journal of Nanoparticle Research, Vol. 1, January 1, 1999, pp. 243-251.</b>					
	GH	<b>Samuelson, L., "Self-Forming Nanoscale Devices", Materials Today, October 22, 2003, pp. 22-31.</b>					
	GI	<b>Ohlsson, B., et al., "Fabrication and characterization of III-V nanowhiskers", MSS10 Conference - Austria, July 23-27, 2001.</b>					
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	HB	<b>WO 01/77726</b>	<b>10/18/01</b>	<b>WIPO</b>			
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	HC	<b>Martensson, T., et al., "Fabrication of Individually Seeded Nanowire Arrays by Vapour-Liquid-Solid Growth", <u>Nanotechnology</u>, No. 14, October 17, 2003, pp. 1255-1258..</b>					
	HD	<b>Burgess, D.S., "Nanowire Heterostructures Form Tunneling Diodes", <u>Photonics Spectra</u>, Vol. 37, No. 2, pp. 3-5.</b>					
	HE	<b>Pettersson, H., et al., "Electrical and Optical Properties of Self-Assembled InAs Quantum Dots in InP Studied by Space-Charge Spectroscopy and Photoluminescence", <u>Phys. Rev. B</u>, Vol. 61, No. 7, February 15, 2000, pp. 4795-4800.</b>					
	HF	<b>Ohlsson, B.J., et al., "Growth and characterization of GaAs and InAs nano-whiskers and InAs/GaAs heterostructures", <u>Physica E</u>, No. 13, March 1, 2002, pp. 1126-1130.</b>					
	HG	<b>Samuelson, L., et al., "Tunnel-Induced Photon Emission in Semiconductors Using an STM", <u>Physica Scripta</u>, Vol. T42, January 1, 1992, pp. 149-152.</b>					
	HH	<b>Seifert, W. et al, "In-Situ Growth of Quantum Dot Structures by the Stranski-Krastanow Growth Mode", <u>Prog. Crys. Growth Charact.</u>, Vol. 33, January 1, 1996, pp. 423-471.</b>					
	HI	<b>Persson, M., "Tight-Binding Simulation of Nanocrystalline Particles and Whiskers", <u>Tekn lic thesis</u>, Lund University, August 1, 2002.</b>					
	HJ	<b>Bjork, M., "Semiconductor Nanowires and Devices", <u>Tekn lic thesis</u>, Lund University, November 1, 2002.</b>					
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	IC	Murphy, C.J., et al., "Controlling the Aspect Ratio of Inorganic Nanorods and Nanowires", <u>Advanced Materials</u> , Vol. 14, No. 1, January 4, 2002, pp. 80-82.					
	ID	Wagner, R.S., et al., "Vapour-Liquid-Solid Mechanism of Single Crystal Growth", <u>Appl. Phys. Lett.</u> , Vol. 4, No. 5, March 1, 1964, pp. 89-90.					
	IE	Canham, L.T., "Silicon Quantum Wire Array Fabrication by Electrochemical and Chemical Dissolution of Wafers", <u>Appl. Phys. Lett.</u> , Vol. 57, September 3, 1990, pp. 1046-1048.					
	IF	Koga, T., et al., "Carrier Pocket Engineering Applied to Strained ....", <u>Appl. Phys. Lett.</u> , Vol. 75, October 18, 1999, pp. 2438-2440.					
*	IG	Koga, T., et al., "Experimental Proof-of-Principle Investigation of Enhanced Z <sub>3d</sub> T in (001) Oriented Si/Ge Superlattices", <u>Appl. Phys. Lett.</u> , Vol. 77, No. 10, September 4, 2000, pp. 1490-1492.					
	IH	Narihiro, M., et al., "Resonant tunneling of electrons via 20 nm scale InAs quantum dot and magnetotunneling spectroscopy of its electronic states", <u>Applied Physics Letters</u> , Vol. 70, No. 1, January 6, 1997, pp. 105-107.					
	II	Pan, Z., et al., "Conduction band offset and electron effective mass in GaInNAs/GaAs quantum-well structures with low nitrogen concentration", <u>Applied Physics Letters</u> , Vol. 78, No. 15, April 9, 2001, pp. 2217-2219.					
	IJ	Ferry, D.K., et al., "Transport in Nanostructures", <u>Cambridge University Press</u> , Hardcover, January 1, 1997, pp. 41-45.					
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*	JC	<u>Ferry, D.K., et al., "Transport in Nanostructures", Cambridge University Press, Hardcover, January 1, 1997, pp. 91-96.</u>					
	JD	<u>Givargizov, E., "Growth of Whiskers by the Vapor-Liquid-Solid Mechanism", Current Topics in Material Science, edited by E. Kaldis, Chapter 3, Vol. 1, January 1, 1978, pp. 79-145.</u>					
	JE	<u>Mullins, J., "News analysis: using unusable frequencies", IEEE Spectrum, Vol. 39, No. 7, July 1, 2002, pp. 22-23.</u>					
	JF	<u>Randall, J.N., et al., "Quantum Dot Devices", in Norman G. Einspruch and William R. Frensley, eds., Heterostructures and Quantum Devices (San Diego, CA: Academic Pres, Inc., 1994) Copyright 1994, p. 420.</u>					
	JG	<u>Markowitz, P.D., et al., "Phase Separation in Al<sub>x</sub>Ga<sub>1-x</sub>As Nanowiskers Grown by the Solution-Liquid-Solid Mechanism", J. Am. Chem. Soc., Vol. 123, April 18, 2001, pp. 4502-4511.</u>					
	JH	<u>Hickmott, T.W., et al., "Negative Charge, Barrier Heights, and the Conduction-Ban Discontinuity in Al<sub>x</sub>Ga<sub>1-x</sub>As Capacitors", J. Appl. Phys., Vol. 57, April 15, 1985, pp. 2844-2853.</u>					
	JI	<u>Mathews, J., et al., "Defects in Epitaxial Multilayers", J. Cryst. Growth, Vol. 27, January 1, 1974, pp. 118-125.</u>					
	JJ	<u>Kovtyukhova, N., et al., "Layer-by-Layer Assembly Rectifying Junctions in and on Metal Nanowires", J. Phys. Chem. B., Vol. 105, August 14, 2001, pp. 8762-8769.</u>					
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	KC	Sakaki, H., "Scattering Suppression and High-Mobility Effect of Size-Quantized Electrons in Ultrafine Semiconductor Wire Structures", <u>Japanese Journal of Applied Physics</u> , Vol. 19, No. 12, December 1, 1980, pp. L735-L738.					
	KD	Scheibel, H. et al., "Generation of Monodisperse Ag- and NaCl Aerosols With Particle Diameters Between 2 and 300 nm", <u>Journal of Aerosol Science</u> , Vol. 14, No. 2, January 1, 1983, pp. 113-126.					
	KE	Knutson, E. et al., "Aerosol Classification by Electric Mobility: Apparatus, Theory, and Applications", <u>Journal of Aerosol Science</u> , Vol. 6, January 1, 1975, pp. 443-451.					
	KF	Miller, M. et al., "Serpentine Superlattice: Concept and First Results", <u>Journal of Crystal Growth</u> , Vol. 111, January 1, 1991, pp. 323-327.					
	KG	Bhat, R., et al., "Patterned Quantum Well Heterostructures Grown by OMCDV on Non-Planar Substrates: Applications to Extremely Narrow SQW Lasers", <u>Journal of Crystal Growth</u> , Vol. 93, January 1, 1988, pp. 850-856.					
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	KI	Givargizov, E.I., "Fundamental Aspects of VLS Growth", <u>Journal of Crystal Growth</u> , Vol. 31, January 1, 1975, pp. 20-30.					
	KJ	Derycke, V., et al., "Carbon Nanotube Inter- and Intramolecular Logic Gates", <u>Nano Letters</u> , Vol. 1, No. 9, August 26, 2001, pp. 453-456.					
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	LC	Iijima, S., "Helical microtubules of graphitic carbon", <u>Nature</u> , Vol. 354, November 7, 1991, pp. 56-58.					
	LD	Yao, Z., et al., "Carbon Nanotube Intramolecular Junctions", <u>Nature</u> , Vol. 402, November 18, 1999, pp. 273-276.					
	LE	Bennett, C., et al., "Quantum information and computation", <u>Nature</u> , Vol. 404, March 16, 2000, pp. 247-255.					
	LF	Michler, P. et al., "Quantum correlation among photons from a single quantum dot at room temperature", <u>Nature</u> , Vol. 406, No. 6799, August 31, 2000, pp. 968-970.					
	LG	Chow, E., et al., "Three-dimensional control of light in a two-dimensional photonic crystal slab", <u>Nature</u> , Vol. 407, October 26, 2000, pp. 983-986.					
	LH	Venkatasubramanian, R., et al., "Thin-Film Thermoelectric Devices with High Room-Temperature Figures of Merit", <u>Nature</u> , Vol. 413, October 11, 2003, pp. 597-602.					
	LI	Bachtold, A., et al., "Scanned probe microscopy of electronic transport in carbon nanotubes", <u>Phys. Rev. Lett.</u> , Vol. 84, No. 26, June 26, 2000, pp. 6082-6085.					
	LJ	Hicks, L.D. et al., "Thermoelectric Figure of Merit of a One-Dimensional Conductor", <u>Phys. Rev. B</u> , Vol. 47, No. 24, June 15, 1993, pp. 16631-16634.					
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	MC	Itskevich, I.E., et al., "Resonant magnetotunneling through individual self-assembled InAs quantum dots", <u>Physical Review B</u> , Vol. 54, No. 23, December 15, 1996, pp. 16401-16404.					
	MD	Reed, M.A., et al., "Observation of Discrete Electronic States in a Zero-Dimensional Semiconductor Nanostructure", <u>Physical Review Letters</u> , Vol. 60, No. 6, February 8, 1988, pp. 535-537.					
	ME	Kapon, E., et al., "Stimulated Emission in Semiconductor Quantum Wire Heterostructures", <u>Physical Review Letters</u> , Vol. 63, No. 4, July 24, 1989, pp. 430-433.					
	MF	Santori, C., et al., "Triggered Single Photons from a Quantum Dot", <u>Physical Review Letters</u> , Vol. 86, No. 8, February 19, 2001, pp. 1502-1505.					
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*	MI	Han, W., et al., "Synthesis of Gallium Nitride Nanorods Through a Carbon Nanotube-Confining Reaction", <u>Science</u> , Vol. 277, August 29, 1997, pp. 1287-1289.					
	MJ	Zhang, Y., et al., "Heterostructures of Single-Walled Carbon Nanotubes and Carbide Nanorods", <u>Science</u> , Vol. 285, September 10, 1999, pp. 1719-1722.					
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	NC	<b>Holmes, J., et al., "Control of Thickness and Orientation of Solution-Grown Silicon Nanowires", <u>Science</u>, Vol. 287, February 25, 2000, pp. 1471-1473.</b>					
	ND	<b>Zhou, C.W., et al., "Modulated chemical doping of individual carbon nanotubes", <u>Science</u>, Vol. 290, November 24, 2000, pp. 1552-1555.</b>					
	NE	<b>Favier, F., et al., "Hydrogen Sensors and Switches from Electrodeposited Palladium Mesowire Arrays", <u>Science</u>, Vol. 293, September 21, 2001, pp. 2227-2231.</b>					
	NF	<b>Bachtold, A., et al., "Logic circuits with carbon nanotube transistors", <u>Science</u>, Vol. 294, November 9, 2001, pp. 1317-1320.</b>					
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	NH	<b>Service, R.F., "Nanowire Fabricators Earn Their Stripes", <u>Science</u>, Vol. 295, No. 5557, January 1, 2002, pp. 946-947.</b>					
	NI	<b>Awschalom, D.D. et al., "Spintronics", <u>Scientific American</u>, Vol. 286, No. 6, June 1, 2002, pp. 66-73.</b>					
	NJ	<b>Henning, P., et al., "Compositional information from amorphous Si-Ge multilayers using high-resolution electron microscopy imaging and direct digital recording", <u>Ultramicroscopy</u>, Vol. 66, January 1, 1996, pp. 221-235.</b>					
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	OC	Wagner, R.S., "VLS Mechanism of Crystal Growth", <u>Whisker Technology, A.P. Levitt, ed., Chapter 3, January 1, 1970, pp. 47-119.</u>					
	OD	Alferov, Z., et al., "For developing semiconductor heterostructures used in high-speed-and opto-electronics", <u>www.nobel.se.physics/laureates/2000/, November 23, 2000.</u>					
	OE	von Klitzing, K., "for the discovery of the quantized Hall effect", <u>www.nobel.se/physics/laureates/1985/, June 16, 2000.</u>					
	OF	Laughlin, R.B., et al., "For their discovery of a new form of quantum fluid with frictionally charged excitations", <u>www.nobel.se/physics/laureates/1998/, June 16, 2000.</u>					
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	OI	Akabori, M. et al., "Selective Area MOVPE Growth of Two-Dimensional Photonic Crystals Having an Air-Hole Array and its Application to Air-Bridge-Type Structures", <u>Physica E, No. 13, January 1, 2002, pp. 446-450.</u>					
	OJ	Melechko, A.V., et al., "Large-Scale Synthesis of Arrays of High-Aspect-Ratio Rigid Vertically Aligned Carbon Nanofibres", <u>Nanotechnology, No. 14, August 19, 2003, pp. 1029-1035.</u>					
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	PD	Takahashi, H., et al., "Formation and Characteristics of 100 nm Scale GaAs Quantum Wires by Selective Area MOVPE", <u>Applied Surface Science</u> , No. 216, January 1, 2003, pp. 402-406.					
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	PF	Kamins, T.I., et al., "Self-Assembled Silicon Nanowires for Integrating Microsystems, Nanoelectronics and Microelectronics", <u>mstnews</u> , 3/03, March 1, 2003.					
	PG	Wu, Y., et al., "Rational Synthesis of Inorganic Nanowires", <u>Abstracts of Papers in the Amer. Chem. Soc.</u> , Vol. 221, April 1, 2001, pp. 108-1ec Part 1.					
	PH	Yang, P., et al., "Nanowires from Vapor Condensation and their Assemblies", <u>Abstracts of Papers in the Amer. Chem. Soc.</u> , Vol. 219, March 26, 2000, pp. 269-Inor Part 1.					
	PI	Huang, M., et al., "Nanowire Array as Potential 2-d Photonic Bandgap Materials", <u>Abstracts of Papers in the Amer. Chem. Soc.</u> , Vol. 221, April 1, 2001, pp. 95-Phys Part 2.					
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	QC	<u>Gates, B., et al., "Synthesis and Characterization of Crystalline Ag<sub>2</sub>Se Nanowires through a Template-Engaged Reaction at Room Temperature", Advanced Fun. Materials, Vol. 12, No. 10, October 1, 2002, pp. 679-686.</u>					
	QD	<u>Yang, P., et al., "Controlled Growth of ZnO Nanowires and their Optical Properties", Advanced Functional Materials, Vol. 12, No. 5, May 2002, pp. 323-331.</u>					
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	SD	<u>Messer, B., et al., "Microchannel Networks for Nanowire Patterning", Journal of the Amer. Chem. Soc., Vol. 122, No. 41, September 29, 2000, pp. 10232-10233.</u>					
	SE	<u>Song, J., et al., "MMo<sub>x</sub>Se, (M=Li<sup>+</sup>,Na<sup>+</sup>,Rb<sup>+</sup>,Cs<sup>+</sup>, NMe<sub>4</sub><sup>+</sup>) Nanowire Formation via Cation Exchange in Organic Solution", Journal of the Amer. Chem. Soc., Vol. 123, No. 39, March 10, 2001, pp. 9714-9715.</u>					
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EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.							

FORM PTO-1449  <u>LIST OF DOCUMENTS CITED BY APPLICANT</u>				Atty. Docket No. A-9837E	Appln. No. 10/613,071		
				Applicant Lars Ivar SAMUELSON et al.			
				Filing Date July 7, 2003	Group 2811		
<b>U.S. PATENT DOCUMENTS</b>							
Examiner Initial		Document Number	Date	Name	Class	Sub-class	Filing Date
	TA						
<b>FOREIGN PATENT DOCUMENTS</b>							
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<b>OTHER</b> (including author, title, date, pertinent pages, etc.)							
	TC	Johnson, J., et al., "Single Gallium Nitride Nanowire Lasers", <u>Nature Materials</u> , Vol. 1, No. 2, September 15, 2002, pp. 106-110.					
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	TE	Wu, Y., et al., "Germanium Nanowire Growth via Sample Vapor Transport", <u>Chem. Mater.</u> , Vol. 12, March 20, 2000, pp. 605-607.					
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